# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



## Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





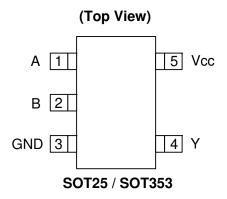
### SINGLE 2 INPUT POSITIVE NAND GATE

#### Description

The 74AHCT1G00 is a single 2-input positive NAND gate with a standard totem pole output. The device is designed for operation with a power supply range of 4.5V to 5.5V. The gate performs the positive Boolean function:

 $Y = \overline{A \bullet B} \text{ or } Y = \overline{A} + \overline{B}$ 

#### **Pin Assignments**



#### Features

- Supply Voltage Range from 4.5V to 5.5V
- ± 8 mA Output Drive at 5.0V
- CMOS low power consumption
- Schmitt Trigger Action at All Inputs Make the Circuit Tolerant for Slower Input Rise and Fall Time.
- ESD Protection per JESD 22
  - o Exceeds 200-V Machine Model (A115-A)
  - Exceeds 2000-V Human Body Model (A114-A)
  - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 100mA per JESD 78, Class II
- SOT25 and SOT353: Assembled with "Green" Molding Compound (no Br, Sb)
- Lead Free Finish / RoHS Compliant (Note 1)

#### **Applications**

- General Purpose Logic
- Wide array of products such as:
  - PCs, networking, notebooks, netbooks, PDAs
  - o Computer peripherals, hard drives, CD/DVD ROM
  - o TV, DVD, DVR, set top box
  - o Phones, Personal Navigation / GPS
  - o MP3 players ,Cameras, Video Recorders

Notes: 1. EU Directive 2002/95/EC (RoHS). All applicable RoHS exemptions applied. Please visit our website at http://www.diodes.com/products/lead\_free.html.

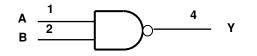


## SINGLE 2 INPUT POSITIVE NAND GATE

### **Pin Descriptions**

Pin Name	Pin No.	Description	
А	1	Data Input	
В	2	Data Input	
GND	3	Ground	
Y	4	Data Output	
V <sub>CC</sub>	5	Supply Voltage	

## Logic Diagram



## **Function Table**

Inp	Output	
Α	В	Y
Н	Н	L
L	Х	Н
Х	L	н



## SINGLE 2 INPUT POSITIVE NAND GATE

### Absolute Maximum Ratings (Note 2)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to 6.5	V
VI	Input Voltage Range	-0.5 to 6.5	V
Vo	Voltage applied to output in high or low state	-0.5 to V <sub>CC</sub> +0.5	V
l <sub>IK</sub>	Input Clamp Current VI<0	-20	mA
I <sub>OK</sub>	Output Clamp Current (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> )	±20	mA
Ι <sub>Ο</sub>	Continuous output current ( $V_O = 0$ to $V_{CC}$ )	±25	mA
I <sub>CC</sub>	Continuous current through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous current through GND	-50	mA
TJ	T <sub>J</sub> Operating Junction Temperature		°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C

Notes: 2. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

## **Recommended Operating Conditions (Note 3)**

Symbol	Parameter		Min	Max	Unit
V <sub>CC</sub>	Operating Voltage		4.5	5.5	V
V <sub>IH</sub>	High-level Input Voltage		2.0		V
VIL	Low-level input voltage			0.8	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current			-8	mA
I <sub>OL</sub>	Low-level output current			8	mA
Δt/ΔV	Input transition rise or fall rate			20	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	125	°C

Notes: 3. Unused inputs should be held at  $V_{CC}$  or Ground.



## SINGLE 2 INPUT POSITIVE NAND GATE

## **Electrical Characteristics**

Or which a l	Demonstern	To at O an dition of	V		25ºC		-40ºC t	o 85ºC	-40ºC to	o 125ºC	11
Symbol	Parameter	Test Conditions	V <sub>CC</sub>	Min	Тур.	Max	Min	Max	Min	Max	Unit
	High Level	Ι <sub>ΟΗ</sub> = -50μΑ	4.5V	4.4	4.5		4.4		4.4		
V <sub>OH</sub>	Output Voltage	I <sub>OH</sub> = -8mA	4.5V	3.94			3.8		3.70		V
V	Low Level	I <sub>OL</sub> = 50μΑ	4.5V		0	0.1		0.1		0.1	V
V <sub>OL</sub>	Output Voltage	$I_{OL} = 8mA$	4.5V			0.36		0.44		0.55	v
lı –	Input Current	V <sub>I</sub> = 5.5V or GND	0 to 5.5V			± 0.1		± 1		± 2	μA
I <sub>CC</sub>	Supply Current	V <sub>I</sub> = 5.5V or GND I <sub>O</sub> =0	5.5V			1		10		40	μA
Ci	Input Capacitance	V <sub>I</sub> = V <sub>CC</sub> – or GND	5.5V		2.0	10		10		10	pF
ΔI <sub>CC</sub>	Additional Supply Current	One input at 3.4V Other inputs at V <sub>CC</sub> or GND	5.5V			1.35		1.5			mA
_	Thermal Resistance	SOT25			204						°0.00
$\theta_{JA}$	Junction-to- Ambient	SOT353	(Note 4)		371						°C/W
0	Thermal Resistance	SOT25			52						°C/M
θ <sub>JC</sub>	Junction-to- Case	SOT353	(Note 4)		143						°C/W

Note: 4. Test conditions for SOT25, and SOT353: Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

### **Switching Characteristics**

 $V_{CC} = 5V \pm 0.5V$  (see Figure 1)

Devemeter	From	то			25ºC		-40ºC t	o 85ºC	-40ºC to	o 125ºC	Unit
Parameter	(Input)	(OUTPUT)		Min	Тур.	Max	Min	Max	Min	Max	Unit
	A or D	V	$C_L=15pF$	0.6	3.6	6.2	0.6	7.1	0.6	8.0	ns
lpd	A or B	ř	$C_L=50pF$	0.6	5.0	7.9	0.6	9.0	0.6	10.0	ns

## **Operating Characteristics**

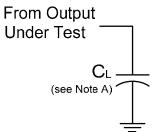
 $T_A = 25 \ ^{o}C$ 

	Parameter	Test Conditions	V <sub>CC</sub> = 5V Typ.	Unit
C <sub>pd</sub>	Power dissipation capacitance	f = 1 MHz No Load	11	pF

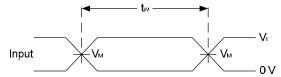


## SINGLE 2 INPUT POSITIVE NAND GATE

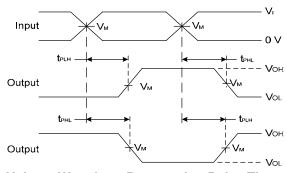
### **Parameter Measurement Information**



Vcc	In	puts	V	0
VCC	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	UL CL
5V±0.5V	3 V	≤3ns	1.5V	15pF
5V±0.5V	3 V	≤3ns	1.5V	50pF



**Voltage Waveform Pulse Duration** 



Voltage Waveform Propagation Delay Times Inverting and Non Inverting Outputs

Notes: A. Includes test lead and test apparatus capacitance. B. All pulses are supplied at pulse repetition rate ≤ 1 MHz.

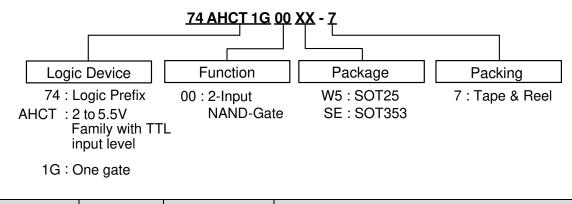
- C. Inputs are measured separately one transition per measurement.
- D. tPLH and tPHL are the same as tpd.

74AHCT1G00 Document number: DS35179 Rev. 1-2



## SINGLE 2 INPUT POSITIVE NAND GATE

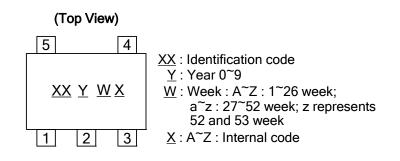
#### **Ordering Information**



	Device	Package Packaging		7" Tape and Reel		
	Device	Code	(Note 5)	Quantity	Part Number Suffix	
<b>B</b>	74AHCT1G00W5-7	W5	SOT25	3000/Tape & Reel	-7	
<b>PD</b>	74AHCT1G00SE-7	SE	SOT353	3000/Tape & Reel	-7	

Notes: 5. Pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.

## **Marking Information**



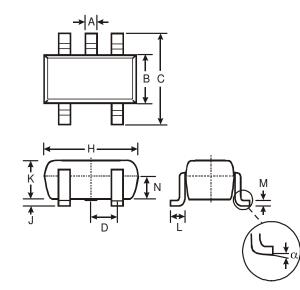
Part Number	Package	Identification Code	
74AHCT1G00W5	SOT25	ZR	
74AHCT1G00SE	SOT353	ZR	



## SINGLE 2 INPUT POSITIVE NAND GATE

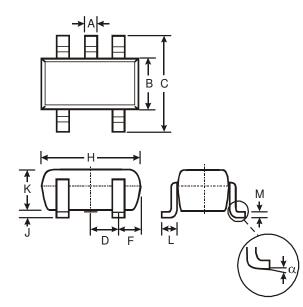
### Package Outline Dimensions (All Dimensions in mm)

#### (1) Package Type: SOT25



	SOT	25	
Dim	Min	Max	Тур
Α	0.35	0.50	0.38
В	1.50	1.70	1.60
С	2.70	3.00	2.80
D			0.95
н	2.90	3.10	3.00
J	0.013	0.10	0.05
К	1.00	1.30	1.10
L	0.35	0.55	0.40
М	0.10	0.20	0.15
Ν	0.70	0.80	0.75
α	0°	8°	
All D	imensi	ons in	mm

#### (2) Package Type: SOT353



	SOT353	
Dim	Min	Max
Α	0.10	0.30
В	1.15	1.35
С	2.00	2.20
D	0.65	Тур
F	0.40	0.45
Н	1.80	2.20
J	0	0.10
К	0.90	1.00
L	0.25	0.40
М	0.10	0.22
α	0°	8°
All Di	mensions	in mm



### SINGLE 2 INPUT POSITIVE NAND GATE

#### IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel.

Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products or systems.

Copyright © 2011, Diodes Incorporated

www.diodes.com